## Freescale Semiconductor Technical Data

# General Purpose Linear Amplifier Module

## Features

- 34.5 dB Typical Gain @ 100 MHz
- Silicon Bipolar Technology
- Class A Operation
- Typical ITO = +44 dBm @ 200 MHz
- Unconditionally Stable Under All Load Conditions

### Applications

- Driver Amplifier in 50 Ohm Systems Requiring High Linearity
- Instrumentation Amplifiers
- Return Path Amplifier on CATV Systems Operating in the 10 to 200 MHz Frequency Range
- Possible Replacement for CA2830C

### Description

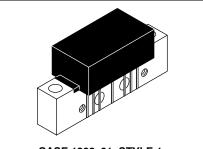
- 24 Vdc Supply, 10 to 200 MHz, General Purpose Linear Amplifier Module
- Replaced MHW1345. There are no form, fit or function changes with this part replacement.
- RoHS Compliant

## Document Number: MHW1345N Rev. 3, 5/2006

**RoHS** 

## MHW1345N

10-200 MHz 34.5 dB 800 mW GENERAL PURPOSE LINEAR AMPLIFIER MODULE



CASE 1302-01, STYLE 1

### Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DC Supply Voltage	V <sub>CC</sub>	28	Vdc
RF Power Input	P <sub>in</sub>	+5	dBm
Operating Case Temperature Range	T <sub>C</sub>	- 20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	- 40 to +100	°C

Table 2. Electrical Characteristics (T<sub>C</sub> = 25°C, V<sub>CC</sub> = 24 V, 50  $\Omega$  system unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Frequency Range	BW	10	_	200	MHz
Gain Flatness (f = 10 - 200 MHz)	G <sub>F</sub>	_	±0.5	±1	dB
Power Gain (f = 100 MHz)	G <sub>p</sub>	33.5	34.5	35.5	dB
Noise Figure, Broadband (f = 200 MHz)	NF	_	3.8	4.5	dB
Power Output — 1 dB Compression (f = 10 - 200 MHz)	P <sub>1dB</sub>	630	800		mW
Power Output — 1 dB Compression (f = 10 - 200 MHz, V <sub>CC</sub> = 28 V)	P <sub>1dB</sub>	1000	1260	_	mW
Third Order Intercept (See Figure 2, f <sub>1</sub> = 200 MHz)	ITO	43	44	—	dBm
Input/Output VSWR (f = 10 - 200 MHz)	VSWR	_	1.5:1	2:1	
Second Harmonic Distortion (Tone at 100 mW, f <sub>2H</sub> = 150 MHz)	d <sub>so</sub>	_	- 60	- 50	dB
Peak Envelope Power (Two Tone Distortion Test — See Figure 2) (f = 10 - 200 MHz @ - 32 dB IMD)	PEP	600	800	_	mW
Supply Current	I <sub>CC</sub>	270	310	330	mA

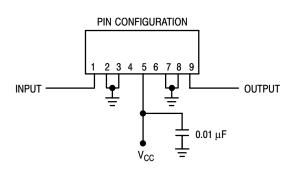


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		11	S21		S12		S22	
Frequency (MHz)	Мад	Ang	Mag	Ang	Mag	Ang	Мад	Ang
10	- 19.3	45.5	34.6	-0.6	-47.0	2.3	-14.5	76.8
50	- 15.6	35.0	34.2	-56.7	-47.5	-30.3	-12.6	45.0
100	- 13.2	34.4	33.9	- 114	-47.9	-62.9	- 10.8	10.7
200	-11.1	30.1	33.5	134	-48.3	-128	-14.9	-42.6

Table 3. S-Parameters (Biased at 24 Volts, T =  $25^{\circ}C$  Z<sub>o</sub> =  $50\Omega$ )

Magnitude in dB, Phase Angle in degrees.





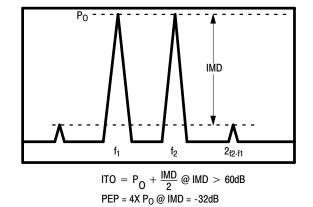
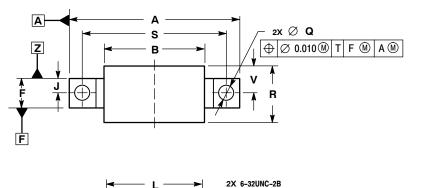
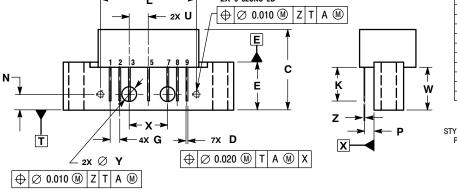


Figure 2. Intermodulation Test

## PACKAGE DIMENSIONS





NOTES: 1. DIMENSIONS ARE IN INCHES. 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN MA			
Α		1.775		45.085		
В		1.085		27.559		
C		0.840		21.336		
D	0.015	0.021	0.381	0.533		
Е	0.465	0.510	11.811	12.954		
F	0.300	0.325	7.62	8.255		
G	0.100 BSC		2.540 BSC			
J	0.15	0.156 BSC		3.962 BSC		
Κ	0.315	0.355	8.001	9.017		
L	1.000 BSC		25.400 BSC			
Ν	0.165 BSC		4.191 BSC			
Ρ	0.100 BSC		2.540 BSC			
Q	0.148	0.168	3.759	4.267		
R		0.600		15.24		
S	1.500 BSC		38.100 BSC			
U	0.200	BSC	5.080 BSC			
۷		0.250		6.350		
W	0.435		11.049			
Х	0.400 BSC		10.160 BSC			
Y	0.152	0.163	3.861	4.140		
Z	0.009	0.011	0.229	0.279		

STYLE 1: PIN 1. RF INPUT 2. GROUND 3. GROUND 4. DELETED 5. VDC 6. DELETED 7. GROUND 8. GROUND 9. RF OUTPUT

CASE 1302-01 **ISSUE E** 

#### How to Reach Us:

Home Page: www.freescale.com

E-mail: support@freescale.com

#### USA/Europe or Locations Not Listed:

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 +1-800-521-6274 or +1-480-768-2130 support@freescale.com

### Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) support@freescale.com

#### Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064 Japan 0120 191014 or +81 3 5437 9125 support.japan@freescale.com

#### Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd. Technical Information Center 2 Dai King Street Tai Po Industrial Estate Tai Po, N.T., Hong Kong +800 2666 8080 support.asia@freescale.com

#### For Literature Requests Only:

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